

## SUPPLEMENTARY INFORMATION

# Ordered Coalescence of Nano-Crystals during Rapid Solidification of Ceramic Melts

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## EXPERIMENTAL METHODS

### 1. Materials

Dense aluminosilicate-zirconia beads of approximately 125 µm diameter and overall chemical composition of 60-70% ZrO<sub>2</sub>, 28-33% SiO<sub>2</sub> and less than 10% Al<sub>2</sub>O<sub>3</sub> were used as precursors. The ceramic beads were prepared by a gas atomization process in which the ceramic melt was gas atomized through a nozzle forming melt droplets that were further rapidly solidified in a water bath.

### 2. Laser sintering

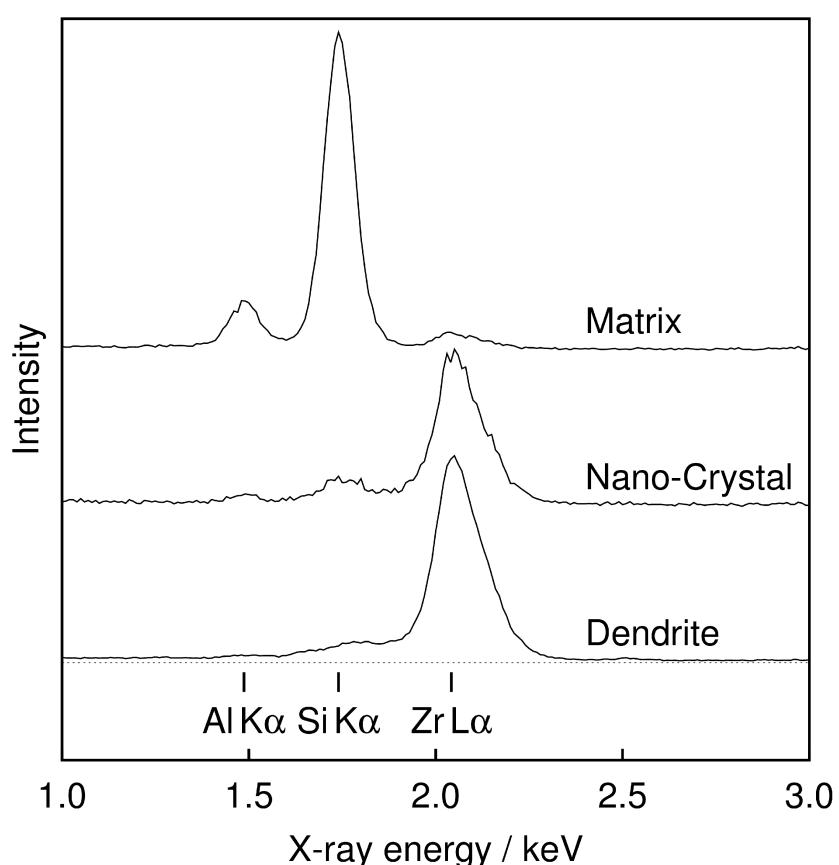
An Yb-fiber laser with 1060-1100 nm wave length and a focused beam diameter of approximately 100 µm was applied. The laser has a maximum power of 200 W, but it turned out that it is sufficient to apply 50 W at an exposure speed of  $\leq$  7000 mm/s to melt the targeted aluminosilicate-zirconia beads. From the melting features we estimate that the peak temperature exceeds the melting point of zirconia (2715°C).

### 3. Microstructure characterization

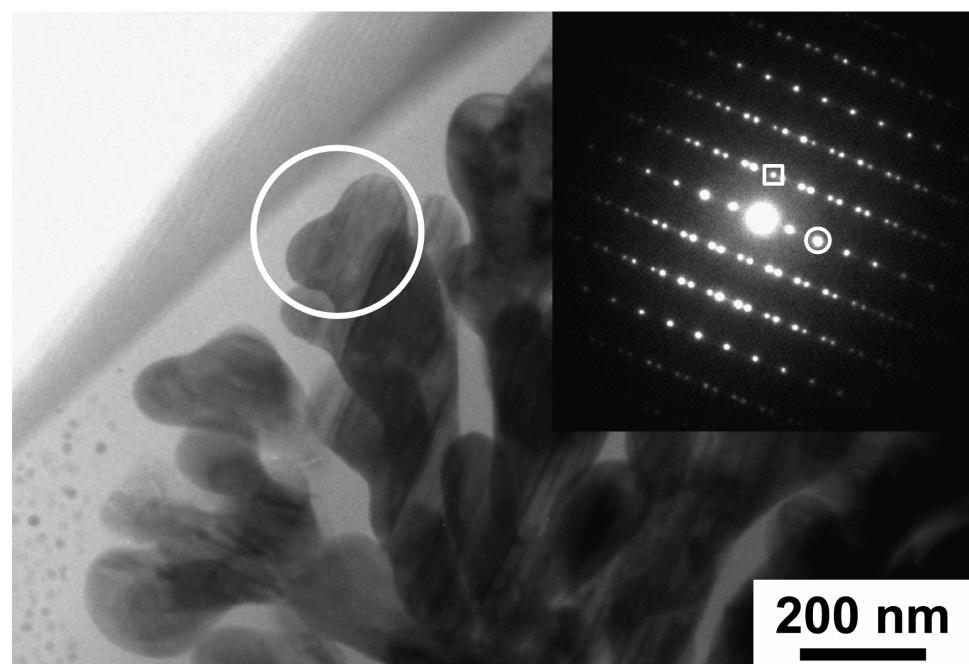
Fracture surfaces and natural surfaces of the laser-sintered bodies were studied using a JSM-7000F (JEOL, Tokyo, Japan) field emission scanning electron microscope. For more detailed studies of the microstructure, thin foils for transmission electron microscopy (TEM) were prepared. Approximately 0.5 mm  $\times$  2.5 mm wide and 0.3 mm thick pieces were cut from the bulk material using a low-speed saw equipped with a diamond wafering blade (Buehler, Lake Bluff, IL, USA), ground to 0.1 mm thickness using diamond abrasives fixed on polymer sheets, and ion-milled to electron transparency using a JEOL IS-09100 ion slicer operated at 5 kV. TEM images were obtained using a JEOL JEM-3010 TEM operated

at 300 kV and recorded using a KeenView CCD camera (Olympus Soft Imaging Systems, Münster, Germany). A JEOL JEM-2100 TEM was used to record EDX spectra at 200 kV accelerating voltage.

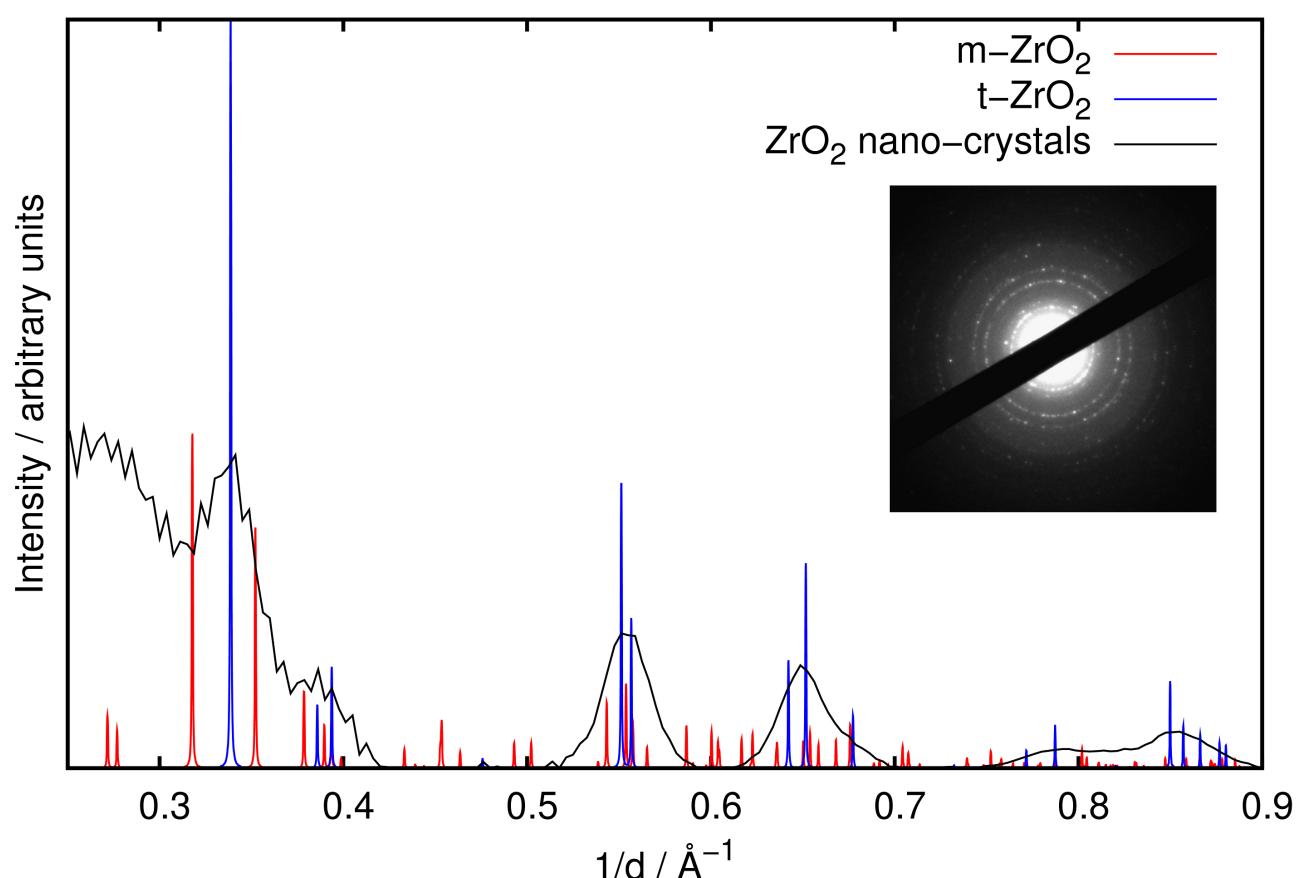
## SUPPORTING DATA



**Figure S1.** EDS spectra of regions of the TEM foil containing a dendritic crystal, an isolated nano-crystal and the glass matrix. While dendritic crystals and nano-crystals are composed of almost pure ZrO<sub>2</sub>, the matrix is essentially free from zirconia and comprises mainly silica and a minor amount of alumina.



**Figure S2.** Dendritic zirconia crystals frequently show a banded contrast in bright field TEM images due to polysynthetic twinning on the (100) plane, which is confirmed by inspecting the selected area electron diffraction pattern (inset) taken along [011] from the region inside the circle. The reflections marked with a circle and a square are indexed 200 and 01-1 (twin component 1), respectively.



**Figure S3.** The inset shows a selected area electron diffraction pattern of a region of the laser sintered aluminosilicate-zirconia composite body containing zirconia nano-crystals embedded in an amorphous aluminosilicate matrix. The diffraction pattern shows rings of intensity from the randomly oriented nanocrystals. The intensity in the rings has been integrated using the program ELD (Zou, X. D.; Y. Sukharev, Y.; Hovmöller, S. *Ultramicroscopy* 1993, **49**, 147-158) and plotted as a function of  $1/d$ . The observed peak positions match the calculated ones for tetragonal zirconia (blue), but not for monoclinic zirconia (red).